

2016/08/31

VTX meeting

Invariant yield of HFe in Run14 AuAu

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✓ Invariant Yields of Heavy Flavor e

Calculation of invariant yield of HFe

- dN_e^{HF}/dp_T can be calculated by published photonic yields (π^0, η, γ)

$$\frac{dN_e^{HF}}{dp_T} = \frac{dN_e^{photonic}}{dp_T} \times R_{NP}(p_T) \times (1 - F_{ke3}(p_T) - F_{J/\psi}(p_T))$$

$$> \frac{dN_e^{photonic}}{dp_T} = \frac{dN_{\pi^0, \eta, \gamma}^{total}}{dp_T} \times R_{DP}(p_T) \times (1 + R_{CD})$$

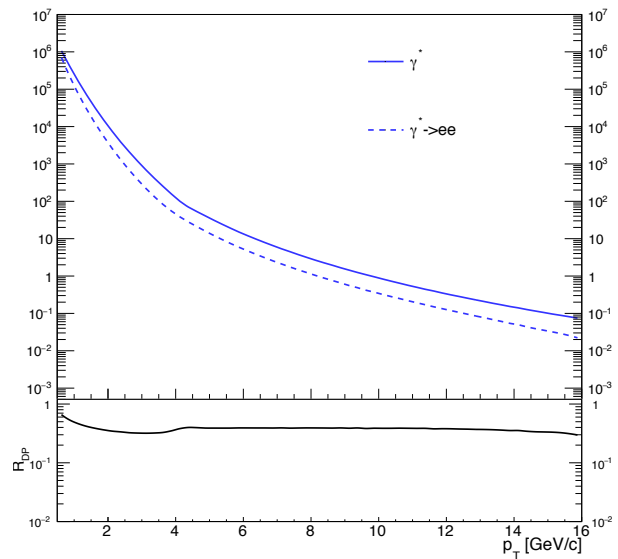
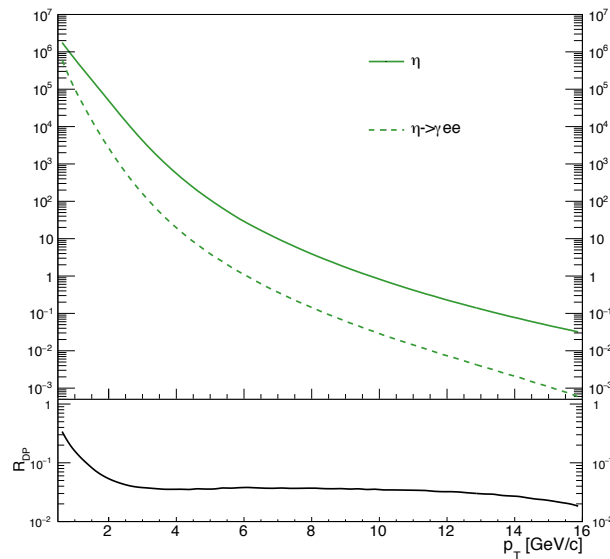
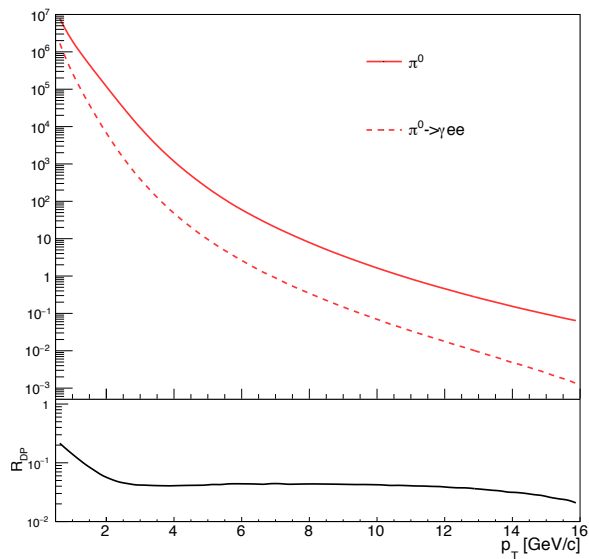
$$\rightarrow R_{DP}(p_T) = \frac{N_e^{dalitz}}{N_{\pi^0, \eta, \gamma}^{total}}, \quad R_{CD} = \frac{N_e^{conv.}}{N_e^{dalitz}} \quad \text{calculated by MC method}$$

> $R_{NP}(p_T)$ can be calculated by data driven

> $F_{ke3}, F_{J/\psi}$ are used previous analysis

$$\frac{dN_e^{HF}}{dp_T} = \frac{dN_{photon}^{total}}{dp_T} \times R_{DP}(p_T) \times (1 + R_{CD}) \times R_{NP}(p_T) \times (1 - F_{ke3}(p_T) - F_{J/\psi}(p_T))$$

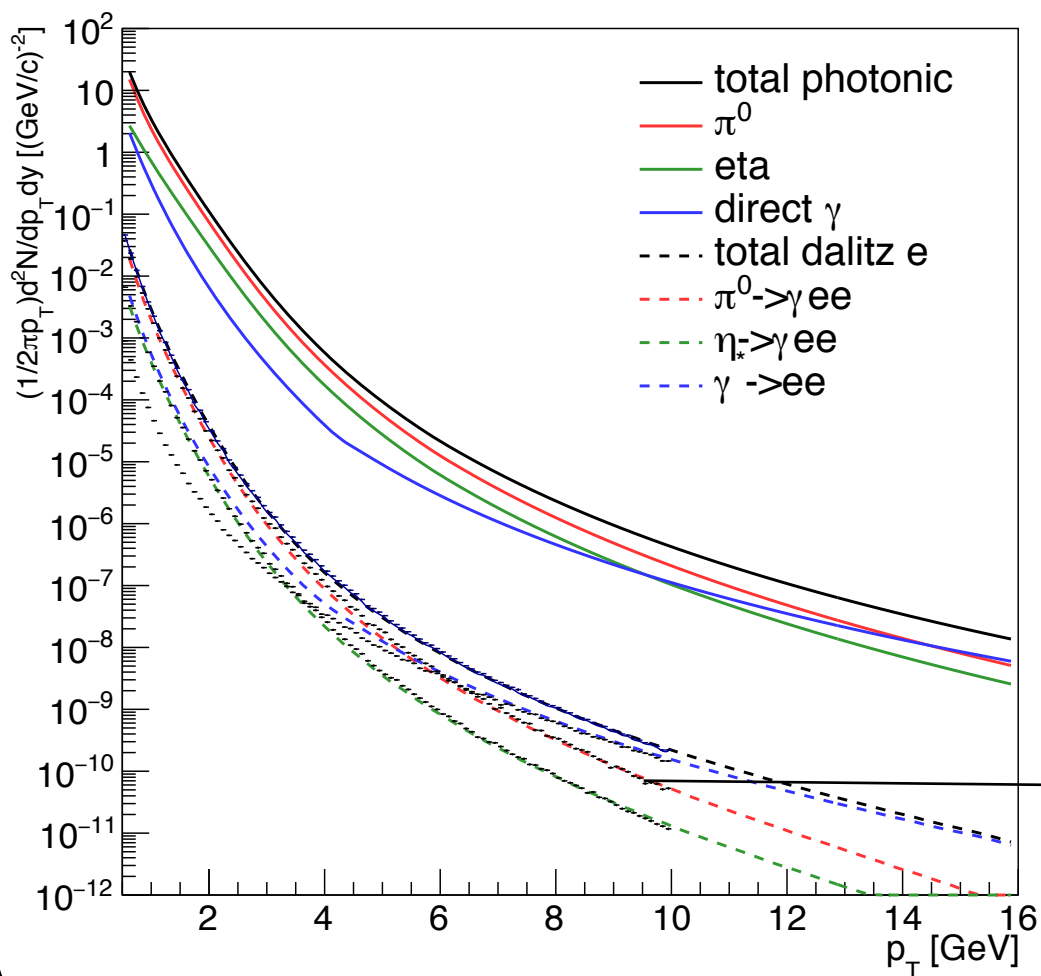
✓ Ratio of Dalitz decay e to photonic souce



- MC simulation
- single sim. \times p_T weight
- Ratio of dalitz e to photonic souce

$$R_{DP}^e = N_{\text{dalitz}}^e / N_{\pi, \eta, \gamma}$$

✓ Invariant yield of dalitz decay e



[Inv. yield of total dalitz e]

- Invariant yield of dalitz decay e can be estimated by MC sim.

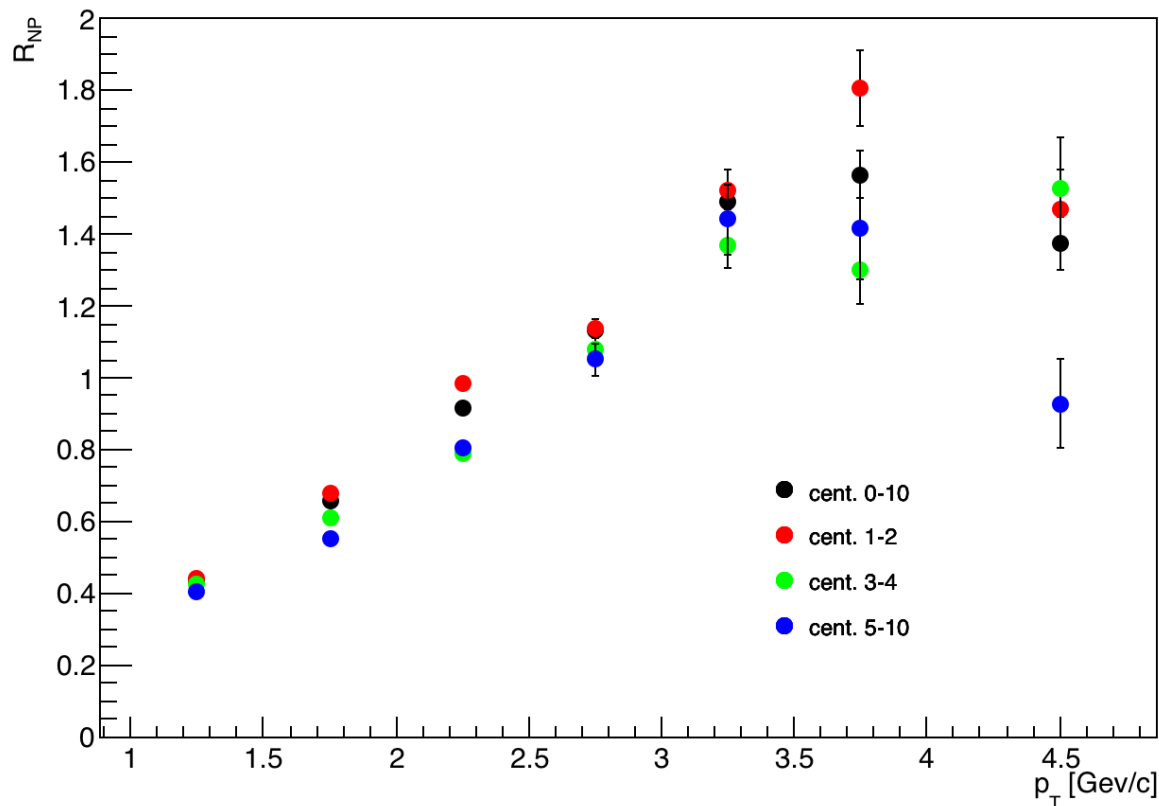
$$dN_e^{\text{dalitz}} / dp_T$$

$$= \text{Yields}_{\pi, \eta, \gamma} \times R_{\text{DP}} \times \text{Branting Ratio}$$

These yield is consistent with Run4 cocktail (black histogram).

✓ Ratio of non-photonic to photonic

Ratio of non-photonic to photonic



$$R_{NP} = N_{NP} / N_P$$

$$N_P = (N_e^{\text{veto}} - \epsilon_R * \epsilon_V * N_e) / \epsilon_R * (1 - \epsilon_V)$$

$$N_{NP} = (\epsilon_R * N_e^{\text{veto}} - N_e) / \epsilon_R * (1 - \epsilon_V)$$

ϵ_V = single veto eff.

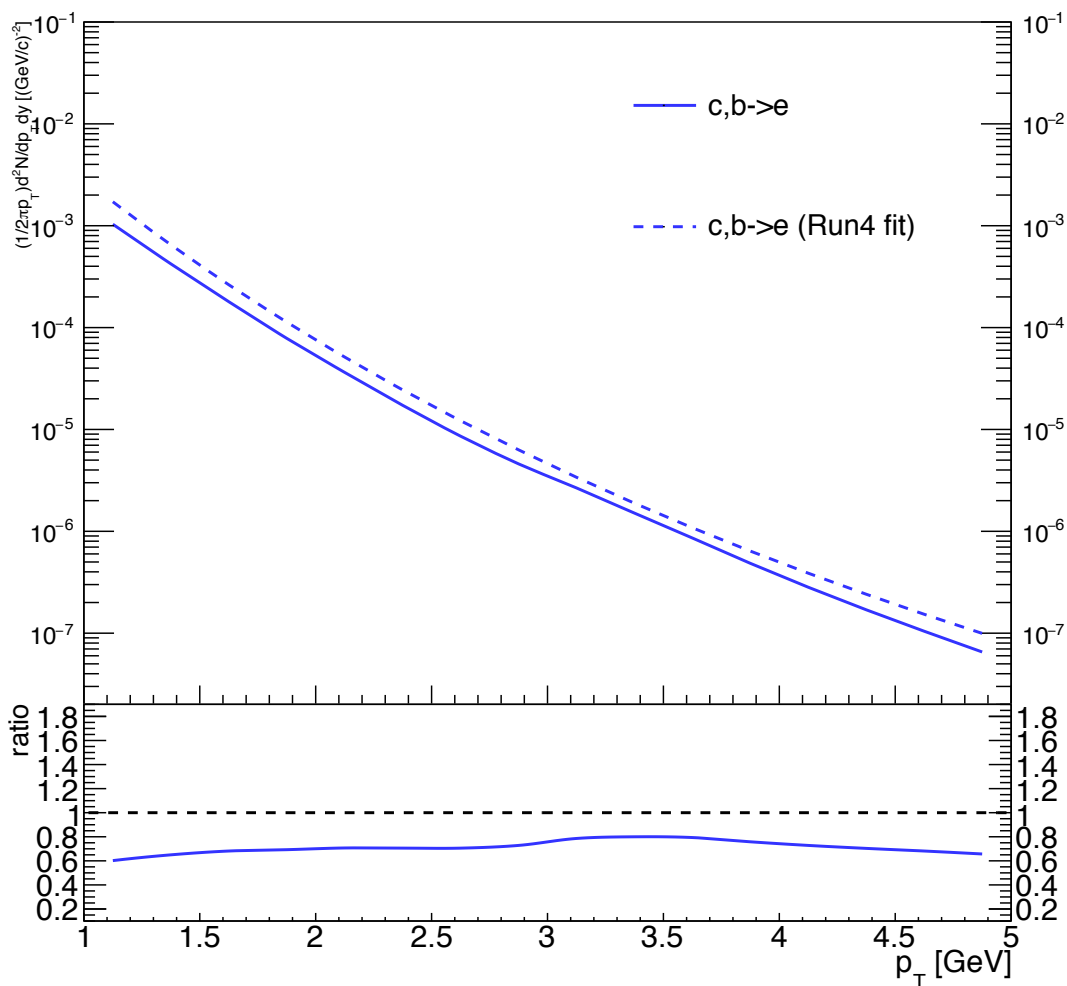
(calculated by MC method)

ϵ_R = random veto eff.

(calculated by data driven)

- Invariant Yield of non-photonic e is calculated by R_{NP} and Inv. Yield of dalitz e and R_{CD}

✓ Invariant yield of HF e

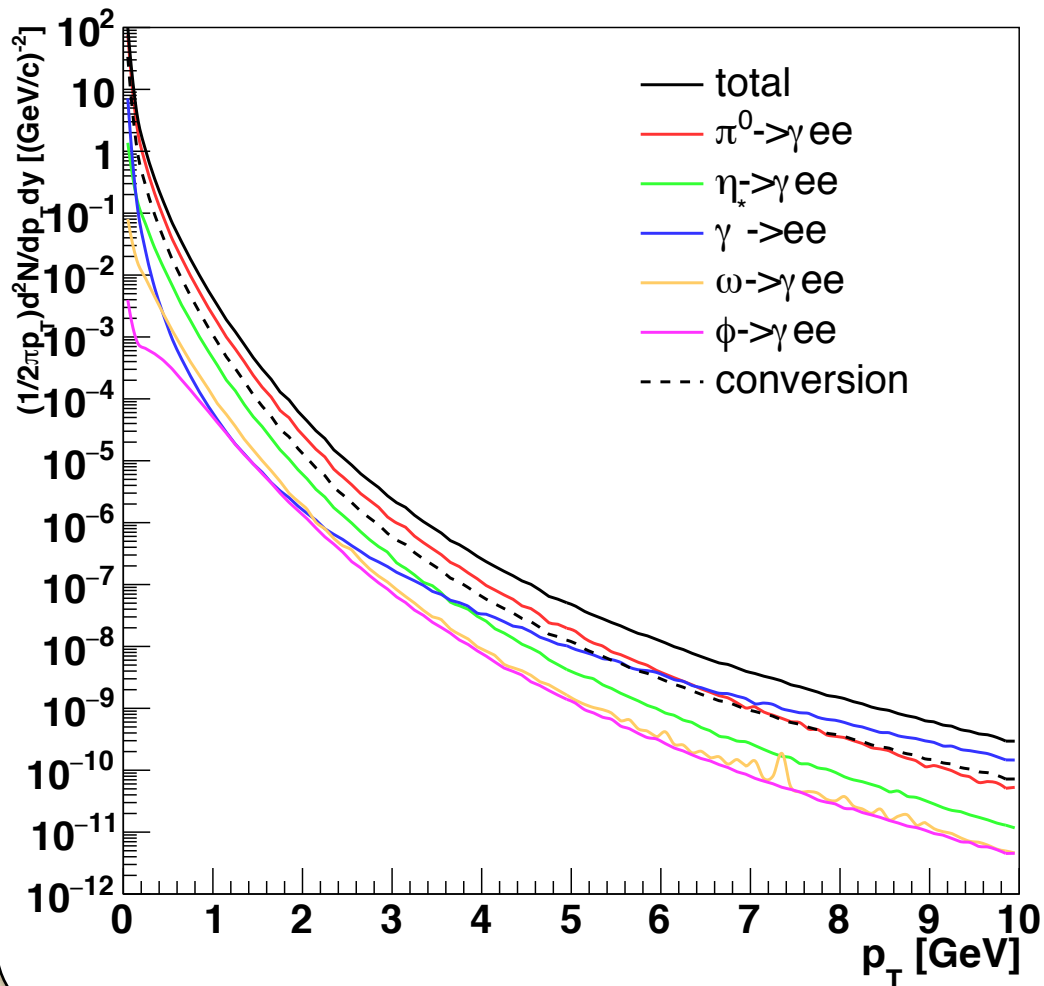


[Invariant yield of HF e]

$$dN_e^{HF}/dp_T = dN_e^{dalitz}/dp_T * (1+R_{CD}) * R_{NP} * (1-F_{ke3}-F_{jpsi})$$

- Run14 Invariant yield is smaller than Run4 fit by 20~30%.
- have not included ω , ϕ yet
- > expect to increase by ~10%

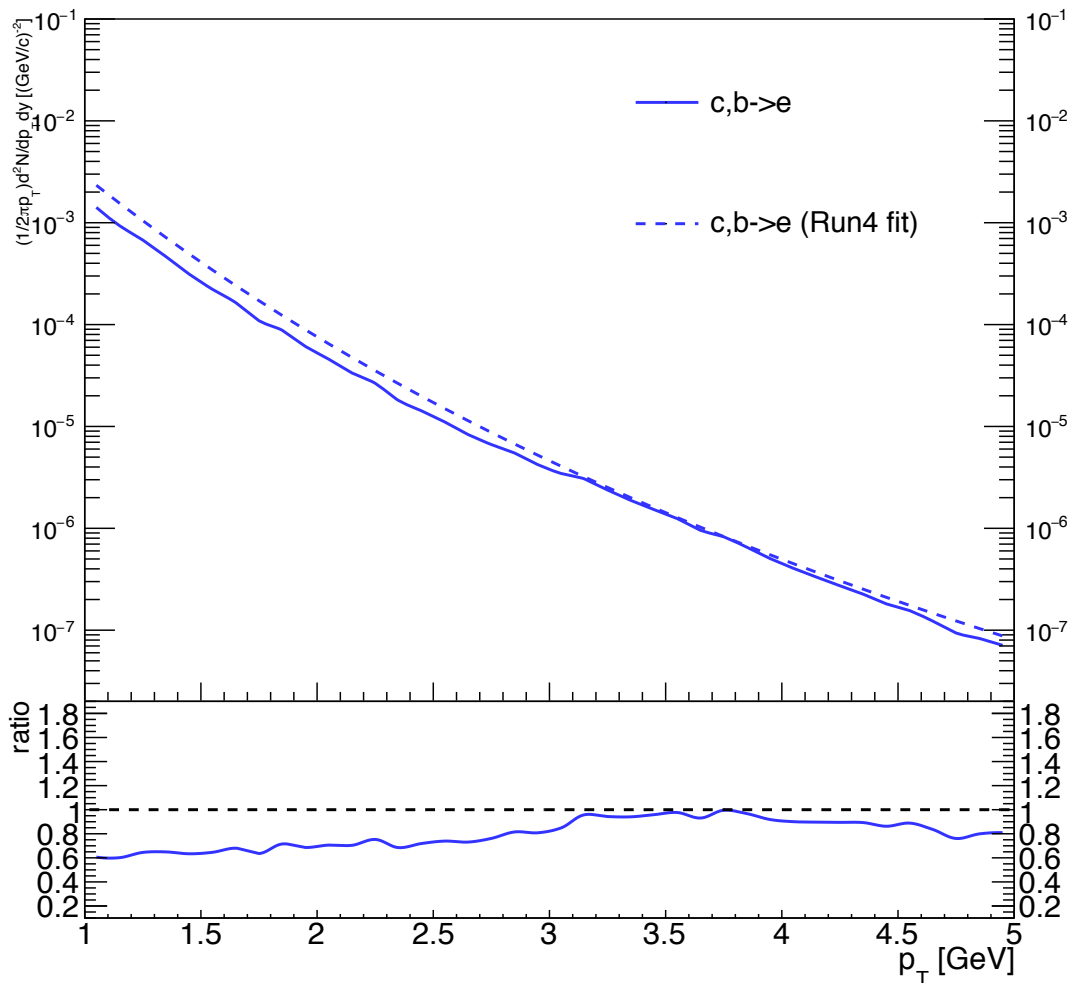
✓ Invariant yield of dalitz e (using Run4 cocktail)



[Run4 cocktail]

- Conversion will be increased by R_{CD} ratio (Run4/Run11)
 - > Run14 $R_{CD} = 1.027$
 - > Run11 $R_{CD} = 0.404$
- conversion $\times (1.027/0.404)$

✓ Invariant yield of HF e (using Run4 cocktail)



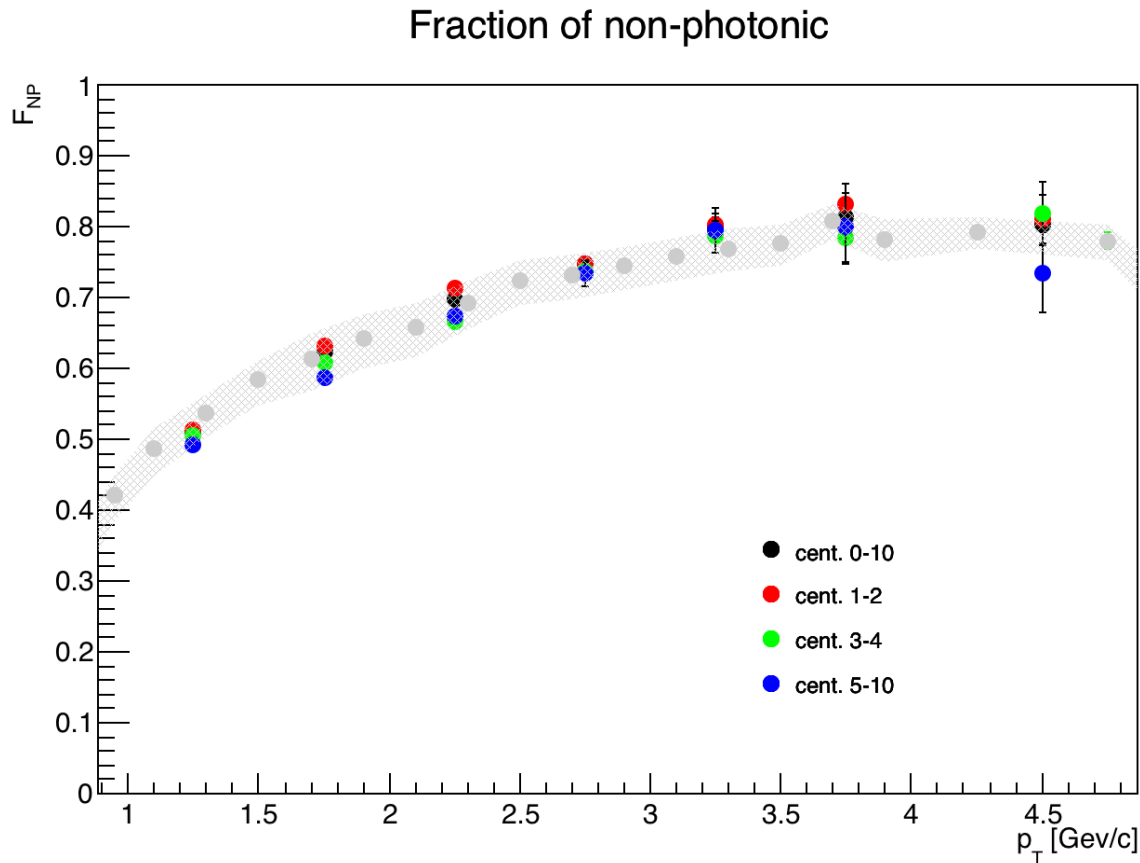
[Invariant yield of HF e]

$$dN_e^{\text{HF}}/dp_T = dN_e^{\text{dalitz}}/dp_T * (1+R_{\text{CD}}) * R_{\text{NP}} * (1-F_{\text{ke}3^-} - F_{\text{jpsi}})$$

- Run14 Invariant yield is smaller than Run4 fit by 0~30%.

✓ backup

✓ Fraction of non photonic electron



[Data driven method]

$$F_{NP} = N_{NP} / (N_{NP} + N_P)$$

$$N_P = (N_e^{\text{veto}} - \epsilon_R * \epsilon_V * N_e) / \epsilon_R * (1 - \epsilon_V)$$

$$N_{NP} = (\epsilon_R * N_e^{\text{veto}} - N_e) / \epsilon_R * (1 - \epsilon_V)$$

ϵ_V = single veto eff.

(calculated by MC method)

ϵ_R = random veto eff.

(calculated by data driven)

Data driven method agree with bootstrap method!!

Data driven method is better than Residual method (using cdphi dist.)

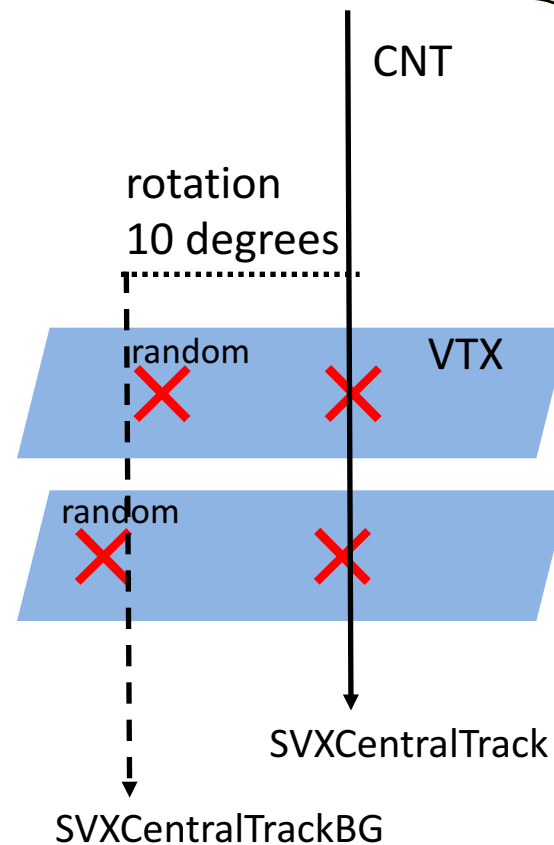
✓ BG: High-multiplicity

✓ High-multiplicity BG

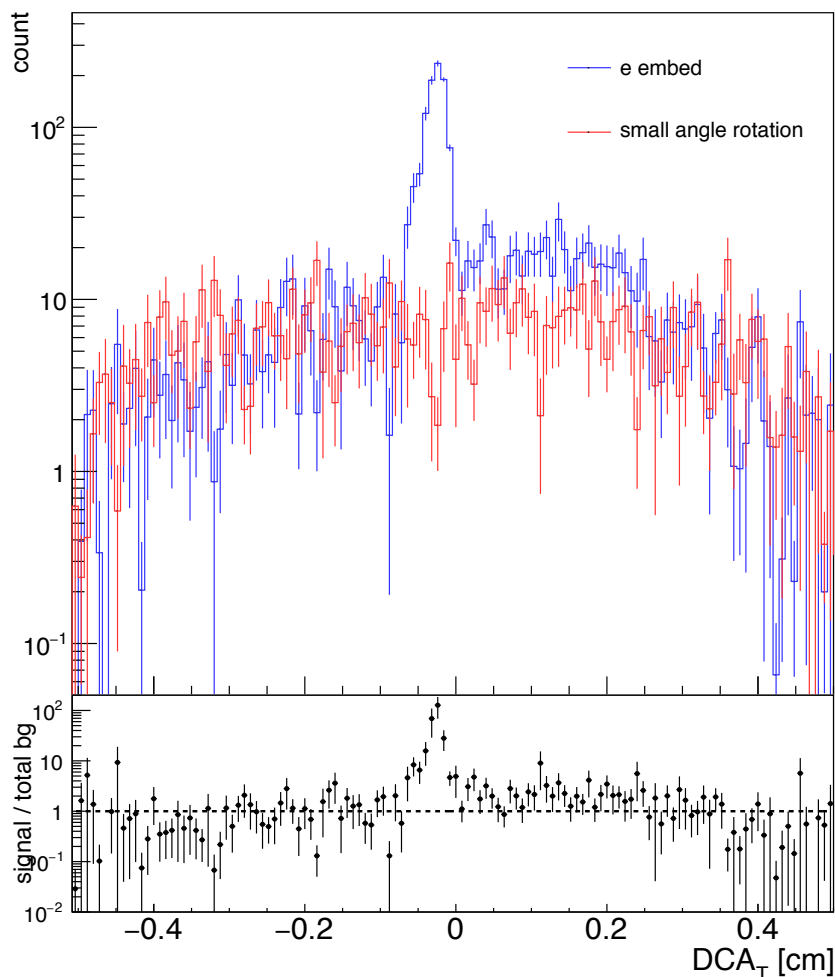
- CNTrack -> true, SVX hit -> fake

✓ Small angle rotation

- reconstruct fake track
- for high-multiplicity BG at VTX
- similar method as RICH swap
- CNT track is rotated 10 degrees at VTX
- $+\phi, -\phi, +\theta, -\theta, +\phi\dots$ (track by track)
- SvxCentralTrackBackList (made by Takashi)
- > reconstructed by SvxCentralTrackBG_VarArray



✓ Embedding study for High-multiplicity BG



+ embedded simulation

- require VTX hit at B0B1 (2hit)
- embedding code has bug
 - > χ^2 distribution is odd
 - > need more investigation

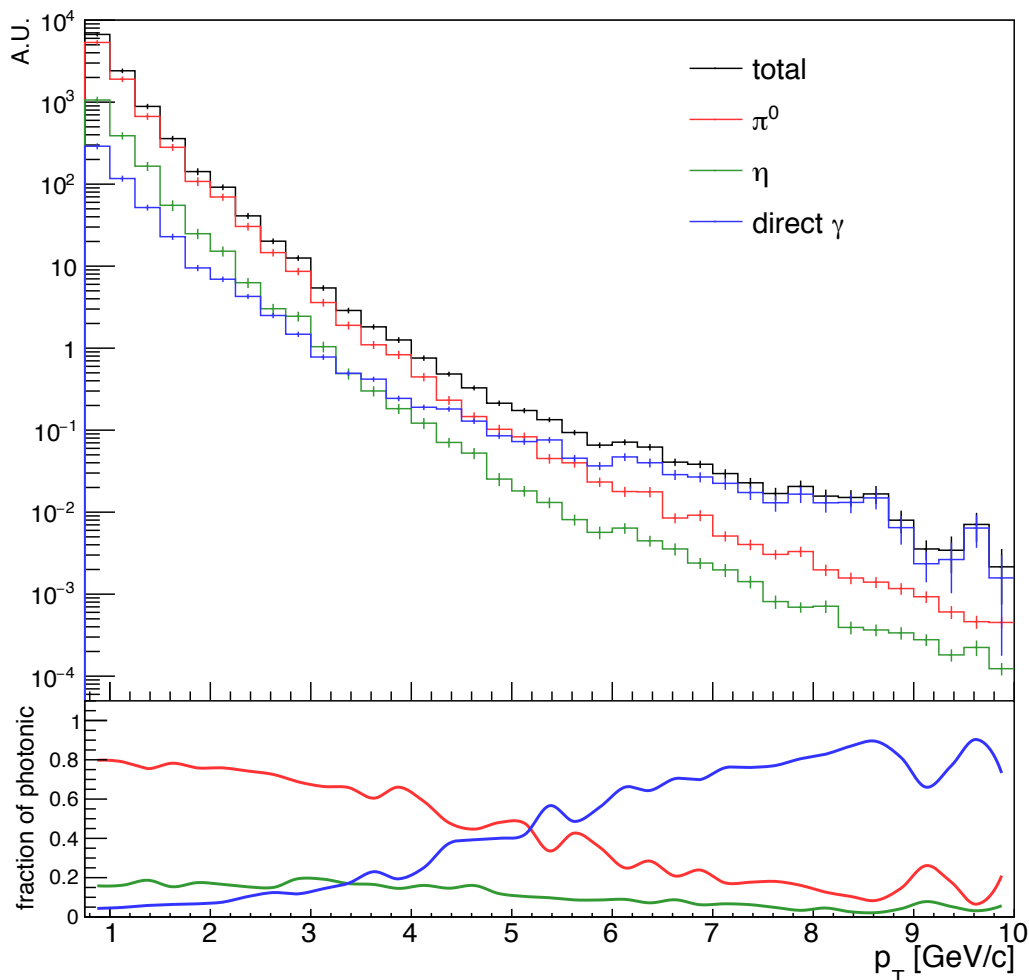
+ small angle rotation

- reproduce high-multiplicity BG almost
- but embedded sim. has asymmetry...

+ To Do

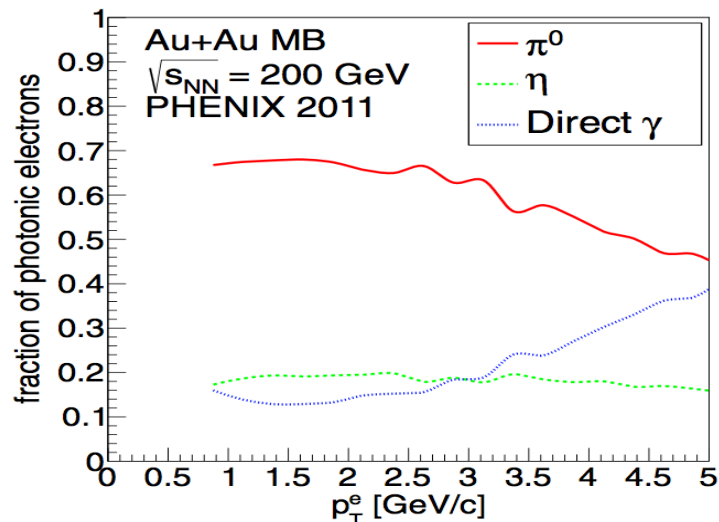
- modify embedding code
- apply to real data

✓ Fraction of photonic electron

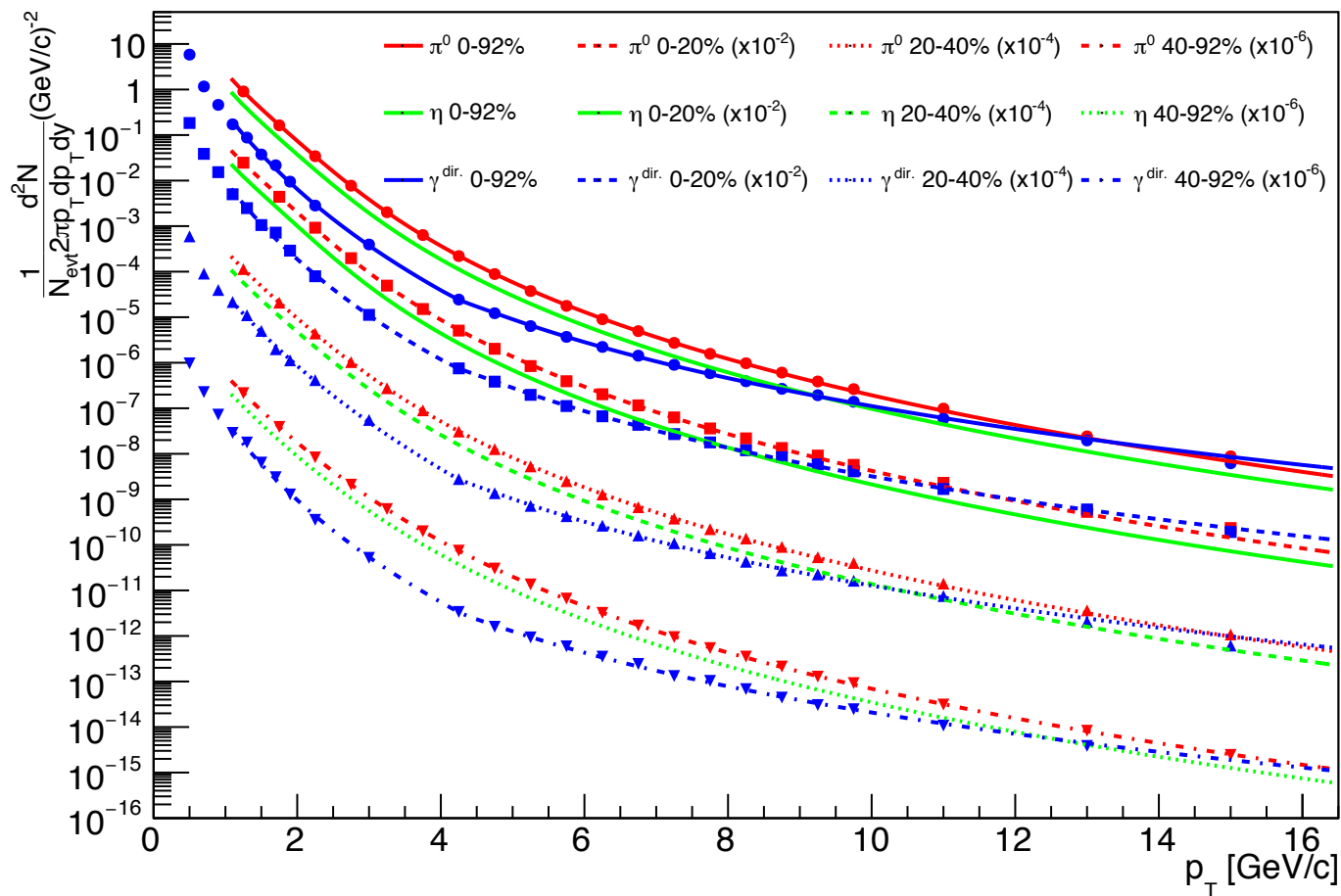


Photonic simulation

- 80M events for each of particles
- applied p_T weight function
- applied veto cut
- calculate fraction of photonic e
- > almost same as that PPG182



✓ Photonic simulation

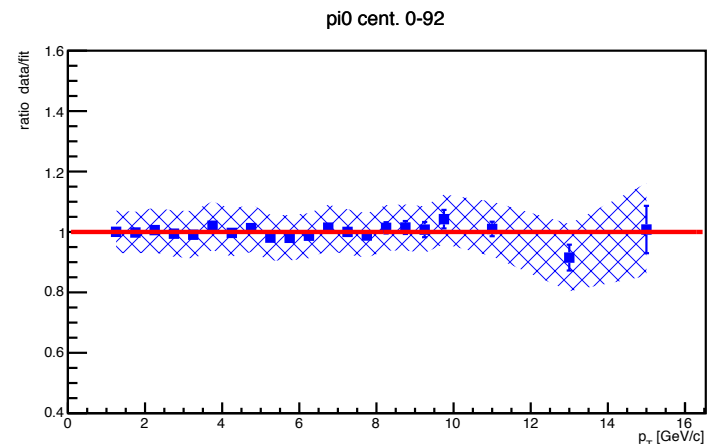
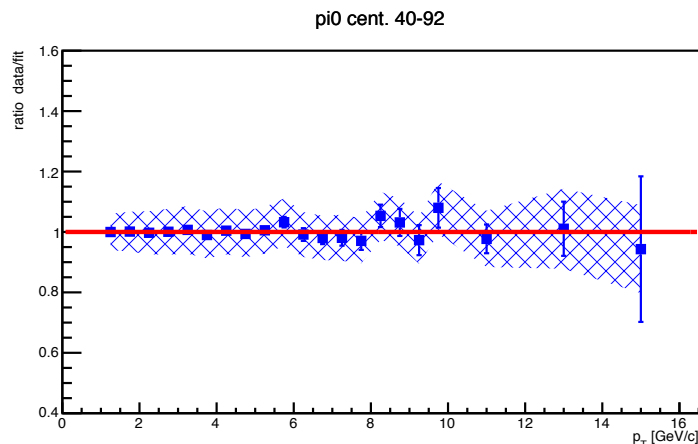
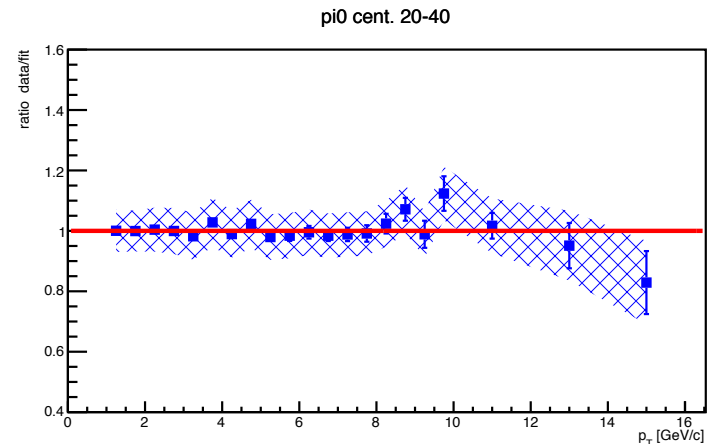
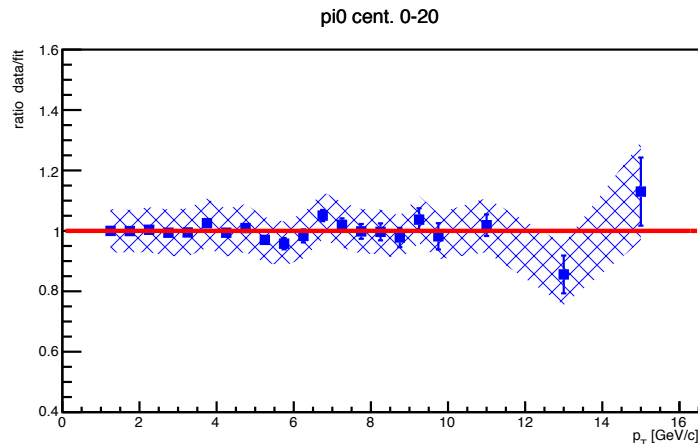


[published data]
 π^0 from PPG
 η from m_T scaling
 $\gamma^{\text{dir.}}$ from PPG

 [p_T weight function]
 - fit mod. hagedorn
 + pow low

 > apply p_T weight
 to mc simulation

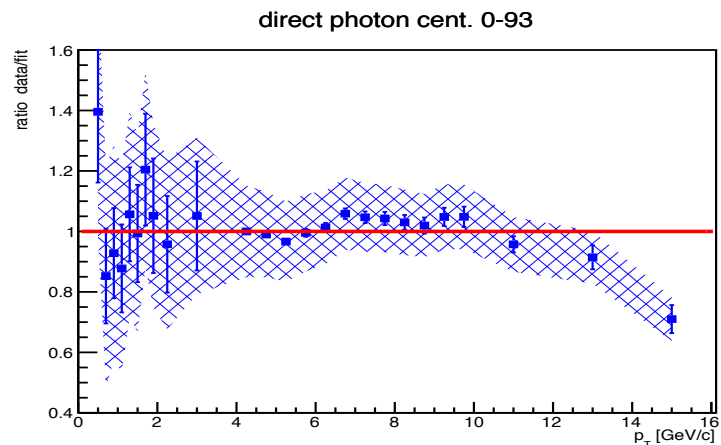
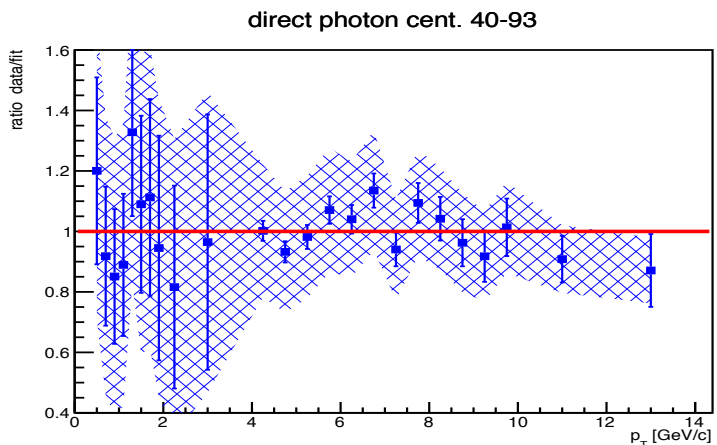
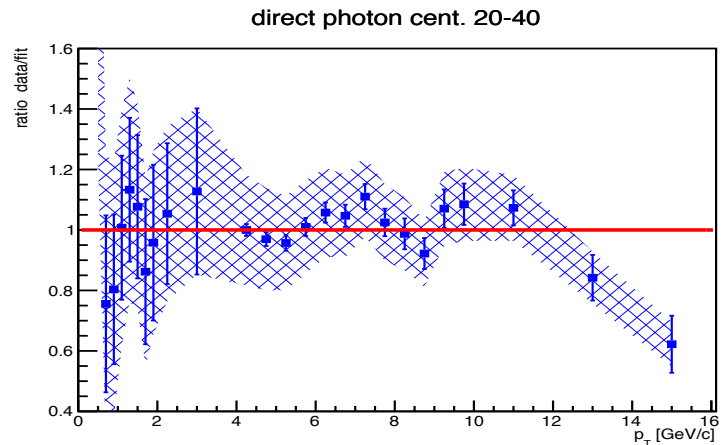
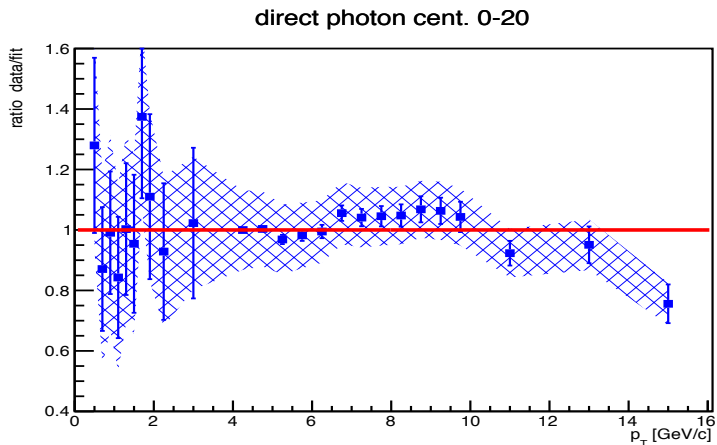
✓ data/fit for π^0 (mod. hagedorn + power low)



- mod. hagedorn + power low agree with data (connected at 9.0 GeV/c)

$$E \frac{d^3 N}{d^3 p} = \frac{1}{1 + \exp((p_T - 9.0)/[7])} \frac{[0]}{(\exp(-[1]p_T - [2]p_T^2) + p_T/[3])^{[4]}} + \frac{1}{1 + \exp((p_T - 9.0)/[7])} [5] p_T^{-[6]}$$

✓ data/fit for direct photon



- mod. hagedorn + power low agree with data (connected at 4.0 GeV/c)

$$E \frac{d^3 N}{d^3 p} = \frac{1}{1 + \exp((p_T - 9.0)/[7])} \frac{[0]}{(\exp(-[1]p_T - [2]p_T^2) + p_T/[3])^{[4]}} + \frac{1}{1 + \exp((p_T - 9.0)/[7])} [5] p_T^{-[6]}$$

